Junction of several weakly interacting quantum wires: a renorm alization group study

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We study the conductance of three or more sem i-in nite wires which meet at a junction. The electrons in the wires are taken to interact weakly with each other through a short-range densitydensity interaction, and they encounter a general scattering matrix at the junction. We derive the renorm alization group equations satis ed by the S-matrix, and we identify its xed points and their stabilities. The conductance between any pair of wires is then studied as a function of physical parameters such as temperature. We discuss the possibility of observing the elects of junctions in present day experiments, such as the four-term inal conductance of a quantum wire and crossed quantum wires.

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I. IN TRODUCTION

Recent advances in the fabrication of sem iconductor heterostructures have m ade it possible to study electronic transport in a variety of geom etries. Recent studies of ballistic transport through a quantum wire (QW) have brought out the important role played by both scattering centers and the interactions between the electrons inside the QW . Theoretical studies using a renorm alization group (RG) analysis show that repulsive interactions between electrons tend to increase the elective strength of the scattering as one goes to longer distance scales [1]; experimentally, this leads to a decrease in the conductance as the tem perature is reduced or the wire length is increased [2]. Considerable e ort has also gone into understanding the e ects of (Ferm i) leads [3], multiple in purities [4] and also contacts [5]. M otivated by the understanding of the e ects of scattering in a one-dimensional problem, we are led to address the following question in this work: what is the e ect of interactions between electrons on the conductance of m ore com plicated geom etrical structures such as three or more QW s meeting at a junction? This problem has been studied before in Ref. [6]; as explained below, our model di ers from theirs in certain ways, and our results are quite di erent. W e will show that for the case of weak interactions, the e ects of a junction (characterized by an arbitrary scattering matrix S) on the conductance can be understood in great detail by using a RG technique introduced in Ref. [7]. We will also complement this with a study of the e ects of certain special kinds of junctions for arbitrary electron interaction to gain a more complete picture.

The plan of the paper is as follows. In Sec. II, we will de ne a junction in term s of a scattering matrix, and we will provide a m icroscopic lattice model of a junction. In

Sec. III, we will discuss an interacting theory of spinless ferm ions in the presence of an S-m atrix at the junction, and we willenum erate som e of the special S-m atrices for which the theory can be bosonized. Sec. IV will contain a derivation of the RG equations for the junction S-m atrix for the case of weak interactions in the wires. In Sec. V, we will study the xed points of the RG equations and their stabilities for the case of three wires meeting at a junction. W herever possible, we will com pare our weak interaction results with the exact results available from bosonization. In Sec. V I, the results of the previous section will be used to study the conductance of a three-wire system as a function of the tem perature in the vicinity of one of the xed points. In Sec. VII, we will consider the tem perature dependence of the four-term inal conductance of a quantum wire (which is often studied experimentally). In Sec. VIII, we will study the xed points and stabilities of the RG equations of a four-wire system, and its four-term inal conductance. In Sec. IX, we will brie y discuss how to extend the previous analysis to the case of spinful ferm ions. We will make some concluding rem arks (including a com parison of ourm odel to that given in Ref. [6]) in Sec. X.

II.A MODEL FOR THE JUNCTION

To study the problem, we rst need a model for the junction. Let us assume that N sem i-in nite wires meet at a junction. The wires are parameterized by coordinates x_i , i = 1;2; ...; N. The junction is the point where all the x_i are simultaneously equal to 0. We adopt the convention that each x_i increases from 0 as one goes outwards from the junction along wire i. Let us denote the incoming and outgoing one-electron wave functions on

w ire i by $_{\text{Ii}}(\mathbf{x}_i)$ and $_{0i}(\mathbf{x}_i)$ respectively (we are ignoring the spin label for the moment); see Fig. 1. For a given wave number k > 0, these wave functions are proportional to the plane waves exp(ikx_i) and exp(ikx_i).

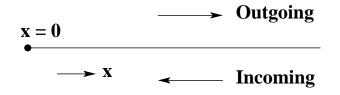


FIG.1. Picture of a single wire showing the incoming and outgoing directions and the junction at x = 0.

The coe cients of the plane waves are related to each other by a N N scattering matrix called S.D enoting the incom ing and outgoing wave functions at the junction by the columns $_{\rm I}$ (0) and $_{\rm O}$ (0), we have the relation

$$_{\circ}$$
 (0) = S $_{I}$ (0) : (1)

C learly, S must be unitary. (If we want the system to be invariant under time reversal, S must also be symmetric). The diagonal entries of S are the rejection amplitudes $r_{\rm ii}$, while the o-diagonal entries are the transmission amplitudes $t_{\rm ij}$ to go from wire j to wire i.

It is useful, though not necessary, to have in m ind a m icroscopicm odelofa junction with an unitary and sym – m etric S-m atrix. A sim ple lattice m odel for this is show n in F ig. 2 for the case of three w ires labeled by i = 1;2;3. The junction is the site labeled as 0, while the sites on the wires have labels going from 1 to 1. The electrons hop from site to site with a hopping constant which is

1 on all bonds except the 3 bonds which join the sites labeled as 1 with the junction; on those three bonds, we take the hopping constants to be the real numbers u_i . In addition, we have a chemical potential at the junction, while the chemical potential on all the other sites is 0. The momenta of the electrons go from to (taking the lattice spacing to be 1); the dispersion relation is given by $E = 2 \cos k$. Since the chemical potential is zero at all sites except one, the system is at half-lling, and the Ferm i points lie at k_F where $k_F = -2$. For incoming momenta k close to k_F , we ind that the entries of the S-m atrix are given by

$$r_{ii} = \frac{2u_i^2}{D} \quad 1;$$

$$t_{ij} = \frac{2u_iu_j}{D};$$

where $D = \frac{X^3}{k^2} + i:$ (2)

This matrix is both unitary and symmetric, although it is not the most general possible matrix with those properties.

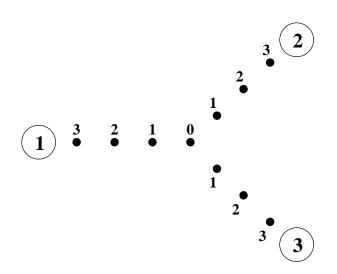


FIG.2. Picture of the lattice m odel for three w ires m eeting at a junction.

III. TOM ONAGA-LUTTINGER LIQUIDS WITHOUT SPIN

Let us now discuss the ferm ion elds in som e m ore detail. We will consider a single wire for the m om ent, so that the labelican be dropped. Since all low -energy and long-wavelength processes are dominated by m odes near the Ferm ipoints k_F , let us write the second-quantized eld (x) (which implicitly contains both ferm ion annihilation operators and wave functions) as

$$(x) = _{I}(x) e^{ik_{F}x} + _{O}(x) e^{ik_{F}x}$$
: (3)

Note that the elds $_{\rm I}$ and $_{\rm O}$ de ned in Eq. (3) vary slow ly on the scale of the inverse Ferm in on entum k_{F}^{1} , since we have separated out the rapidly varying functions exp($ik_F x$). We will henceforth use the notation Iand o for these slow ly varying second-quantized elds, rather than the incoming and outgoing elds de ned earlier. For these elds, we will only be interested in Fourier components with momenta k which satisfy $k_j < k_F$. W e can then m ake a linear approximation for the dispersion relations which take the form E =hy-k for the elds $_{0}$ and $_{T}$ respectively, where v_{F} is the Ferm i velocity. (For instance, for the lattice model discussed above, $v_F = 2 \sin k_F$). We will also assume that the entries of the S-m atrix do not vary with k in the limited range of m om enta that we are interested in.

W e now introduce a model for interactions between electrons. Let us consider a short-range density-density interaction of the form

$$H_{int} = \frac{1}{2} \qquad dxdy (x) V (x y) (y); \qquad (4)$$

where $V\left(x\right)$ is a real and even function of x , and the

density is given in term softhe ferm ion eld as (x) = y(x) (x). Using Eq. (3), we denote that

We can now rewrite the interaction in Eq. (4) in a simple way if V (x) is so short-ranged that the arguments x and y of the two density elds can be set equal to each other wherever possible. [In doing so, we will be ignoring terms which have scaling dimension greater than 2, and are therefore irrelevant in the RG sense. We note that the assumption of a short-ranged interaction is offen made in the context of the Tom onaga-Luttinger liquid description of systems of interacting fermions in one dimension.] U sing the anticom mutation relations between di erent fermion elds, we obtain

$$H_{int} = g_2 \quad dx \quad \int_{I}^{y} \int_{O}^{y} f_{O} f_{O}$$

where g_2 is related to the Fourier transform of V (x) as $g_2 = \vec{\nabla}$ (0) $\vec{\nabla}$ (2k_F). Note that g_2 is zero if V (x) is a -function; so V (x) should have a nite range in order to have an e ect.] Thus the interaction depends on a single parameter g_2 on each wire. Dierent wires may have dierent values of this parameter which we will denote by g_{2i} . For later use, we de ne the dimensionless constants

$$i = \frac{g_{2i}}{2 hv_F} ; \qquad (7)$$

where we assume that the velocity $v_{\rm F}\,$ is the same on all wires.

For many problems involving a Tom onaga-Luttinger liquid, it is useful to bosonize the theory [8,9]. For spinless ferm ions, the bosonic theory is characterized by two quantities, namely, the velocity of the bosonic excitations v, and a dimensionless parameter K which is a measure of the interactions between the ferm ions. (Typically, K governs the exponents which appear in the power-law fall-o s of various correlation functions in the theory). For a model de ned on the entire real line with the interaction parameter g_2 or de ned above, we nd that [8]

$$v = v_F (1 ^2)^{1=2}$$
;
 $K = \frac{1}{1+} ^{1=2}$: (8)

Thus K = 1 for noninteracting fermions, while K < 1 for short-range repulsive interactions. For weak interactions, we see that $v = v_F$ while K = 1 to rst order in . In this work, we will be interested in the case in which the interactions are weak and repulsive, i.e., the parameters $_i$ are all positive and sm all.

A lthough bosonization is a very powerful technique, it is not always possible to bosonize a system of interacting ferm ions with boundaries. In particular, for our system of interest, i.e., three orm ore sem i-in nite wires meeting at a junction with some arbitrary S-matrix de ned at that point, bosonization is a di cult task in general. The reason is that although one can always nd linear com binations of the incom ing and outgoing ferm ion elds which unitarily diagonalize the S-matrix, the four-ferm ion interactions in the bulk of the wires are generally not diagonal in terms of the same linear com binations. C onversely, the interactions in the bulk of the wires can be bosonized, but it is then generally not clear what boundary conditions should be imposed on the bosonic elds at the junction.

However, it is possible to bosonize the system easily for some special forms of the S-m atrix at the junction. For the case of three w ires, there seem to be only six such forms. These are as follows.

(a) Case I: Here $jr_{11}j = jr_{22}j = jr_{33}j = 1$, and all the other entries of the S-m atrix are zero. This can be realized by the lattice model of Fig. 2 if we take the limit

! 1 . This case corresponds to the three wires being disconnected from each other. Each wire can then be bosonized by an unfolding technique described in R ef. [9].

(b) Cases II-IV: In case II, $j_{r_{33}} j = j_{12} j = j_{21} j = 1$, and all the other entries of S are zero. This can be realized by our lattice model if we set $u_3 = 0$ and $u_1 = u_2 \notin 0$. This corresponds to wire 3 being disconnected from wires 1 and 2; the latter two have perfect transm ission into each other. W ire 3 can be bosonized as in case I, while wires 2 and 3 can be bosonized as a single in nite wire. Sim ilarly, there are two other cases, called cases III and IV, which are obtained from case II by cyclically permuting the three wires. W e note that cases I - IV are all invariant under time reversal, if we choose all the entries of the S-m atrix to be real.

(c) Cases V-VI: In case V, $j_{21}j = j_{32}j = j_{13}j = 1$, and all the other entries of S are zero. No matter how the phases of the three non-zero entries of S are chosen, this is not invariant under time reversal. (Therefore it cannot be realized by our lattice model for any choice of the parameters u_i ; and k_F). This can be thought of as three in nite wires with chiral elds; for instance, one such wire is the incoming eld along wire 1 which transmits perfectly into the outgoing eld along wire 2. Finally, we have case VI obtained by time reversing case V; nam ely, $j_{12}j = j_{23}j = j_{31}j = 1$, and all the other entries of S are zero. Cases V and VI can both be bosonized.

Before ending this section, we would like to make some remarks about the physical applicability of cases V and VI. If we think of the three wires as having nite widths, with the incoming and outgoing waves running along two di erent edges of each wire, then the forms of the S-matrices in cases V and VI are very similar to those describing the edge states of a quantum H all system . How - ever, the value of K in a quantum H all system is xed by

the lling fraction of the (two-dimensional) bulk of the system, not by the interaction between the edge states. (In fact, the interactions between the states at the opposite edges of a quantum H all system are offen ignored because of their spatial separation). In contrast to this, ourm odelof the Tom onaga-Luttinger liquids in the wires and our derivation of the RG equations for the S-m atrix given below both depend on the short-range interaction between the incom ing and outgoing modes on each wire. Hence the results obtained by us may not be applicable to quantum H all system s.

IV . RENORMALIZATION GROUP EQUATIONS FOR THE S-MATRIX

Rather than employ bosonization to study the case of an arbitrary S-matrix, we use an instructive and physically transparent method introduced in Ref. [7] to directly obtain RG equations for the entries of the S-m atrix in the presence of electron interactions (provided that the interactions are weak). The basic idea of this method is the following. In the presence of a non-zero re ection am plitude rii, the density of noninteracting ferm ions in wire i has Friedel oscillations with wavenum ber $2k_F$. W hen a weak interaction is turned on, an electron scatters from these oscillations by an amount proportional to the parameter i. Yue et al use this idea to derive the RG equations for an arbitrary S-m atrix located at the junction of two sem i-in nite wires. In the lim its of both weak scattering $(r_{11} ! 0)$ and strong scattering $(r_{11} j ! 1)$, their results reduce to those known from bosonization [1,9]. We will use the same idea for a junction of more than two wires. Not surprisingly, we will nd that the results are much richer than those for two wires.

Let us brie y present the method of Yue et al. We ist derive the form of the density oscillations in one particular wire given that there is a rejection coe cient r for waves coming in along that wire. For a momentum in the vicinity of $k_{\rm F}$, we can write the wave function in the form

$$_{k}(x) = e^{i(k+k_{F})x} + r e^{i(k+k_{F})x}$$
; (9)

where $j_{\rm k}\,j\,<\,<\,k_{\rm F}$. In the ground state of the noninteracting system , the density is given by

<
$$(x) > = \int_{1}^{Z_{0}} \frac{dk}{2} + \int_{k}^{2} (x) + \int_{k}^{2} (x) (x) ;$$
 (10)

where we have used the fact that only states with energy less than E_F (i.e., m on enta less than k_F) are occupied, and we have extended the lower limit to 1 for convenience. (A lternatively, we can impose a cut-o at the lower limit of the form exp(k), and take the limit ! 0 at the end of the calculation). We then nd that has a constant piece $_0$ (which can be eliminated by norm al

ordering the density operator), and a x-dependent piece given by

< (x) >
$$_{0} = \frac{1}{4 x} (r^{2} e^{i2k_{F}x} r e^{i2k_{F}x}) :$$
 (11)

U sing the expression in (5), we see that the expectation value < $y_{I} = 1 + y_{O} = 0$ > is a constant, while

$$< \begin{array}{ccc} y \\ 0 & I \end{array} > = \frac{ir^{2}}{4 x}; \\ < \begin{array}{ccc} y \\ I & 0 \end{array} > = \frac{ir}{4 x}: \end{array} (12)$$

Note that there is also a contribution to (x) from the waves transmitted from the other wires; however those are independent of x and can be absorbed in $_0$. Thus the Friedeloscillations Eq. (11) in a given wire only arise from relections within that wire.

Next we derive the rejection of the fermions from the Friedel oscillations, using a Hartree-Fock decomposition of the interaction in Eq. (6). The rejection is caused by the following terms in the decomposition

$$H_{int} = g_{I} dx (< \frac{y}{0} I > \frac{y}{I} 0$$

$$= \frac{ig_{2}}{4} \int_{0}^{Z_{I}} \frac{dx}{x} (r^{2} I_{I} 0 r 0 I); (13)$$

where we have used (12) to write the second equation. Now we can derive the amplitude to go from a given incoming wave with momentum k to an outgoing wave (or vice versa) under the action of exp($iH_{int}t$). The amplitude is given by

$$i \frac{dk^{0}}{2} 2 \quad (E_{k} \quad E_{k^{0}}) \text{ jutgoing}; k^{0} > \\ < \text{outgoing}; k^{0} \text{jH}_{\text{int}} \text{ jincom ing}; k > \\ = \text{ jutgoing}; k > \frac{ig_{2}r}{4 \text{ hv}_{F}} \int_{0}^{Z} \frac{dx}{x} e^{i2kx}; \quad (14)$$

where we have used Eq. (13), the dispersion relation $E_k = hv_F k$ (so that $(E_k \quad E_{k^\circ}) = (1=hv_F) (k \quad k)$), and the wave functions exp(ikx) of the outgoing and incoming waves respectively. The integral over x in (14) is divergent at the lower end; we therefore introduce a short-distance cut-o d there. The amplitude in (14) then reduces to

$$\frac{r}{2} \ln (kd)$$
(15)

plus pieces which remain nite as kd! 0; we have used Eq. (7) here. Similarly, the amplitude to go from an outgoing wave to an incoming wave is given by

$$\frac{r^2}{2} \ln (kd) : \qquad (16)$$

These re ections from the Friedel oscillations can then be combined along with the S-m atrix at the junction to calculate the corrections to the S-m atrix. For instance, consider r_{ii}. To rst order in the interaction parameters i, this gets corrections from the following processes. An incoming wave on wire i can either (i) turn into an outgoing wire on the same wire with the amplitude in (15) (with r replaced by r_{ii} in that expression), or (ii) get re ected from the junction with amplitude r_{ii} thereby tuming into an outgoing wave, tum back into an incom ing wave according to (16), then get re ected again from the junction, or (iii) transm it through the junction into wire j (with j€ i) with am plitude t_{ii}, turn from an outgoing wave to an incom ing wave on wire j according to (16) (with r replaced by r_{ij}), then transm it back through the junction to wire i with amplitude t_{ij} . The correction to r_{ii} is therefore

$$d\mathbf{r}_{ii} = A_{ii}\ln(\mathbf{k}d);$$
where $A_{ii} = \frac{1}{2} \begin{bmatrix} \mathbf{r}_{ii} + \mathbf{r}_{ij}\mathbf{r}_{ii} \\ X \\ + \mathbf{r}_{jt_{ij}}\mathbf{r}_{jj}^{2}\mathbf{t}_{ji} \end{bmatrix}$: (17)

Similarly, the transm ission amplitude t_{ji} from wire i to wire j can get corrections from the following processes. The incoming wave on wire i can either (i) get rejected from the junction with amplitude r_{ii} , turn back into an incoming wave according to (16), and then transmit into wire j with amplitude t_{ji} , or (ii) transmit into to wire j rst, turn into an incoming wave on wire j according to (16), then get rejected from the junction with amplitude r_{jj} , or (iii) transmit into a wire k (with k \notin i; j), turn into an incoming wave in wire k according to (16) (with r replaced by r_{kk}), then transmit into wire j with amplitude t_{ik} . Hence the correction to t_{ij} is

$$dt_{ji} = A_{ji}\ln(kd);$$
where $A_{ji} = \frac{1}{2} \begin{bmatrix} it_{ji}jr_{ii}j + jr_{jj}jt_{ji} \\ X \\ + k t_{jk}r_{kk}^{2}t_{ki}]:$ (18)

Y use et althen derive the RG equations for the S-m atrix which is now considered to be a function of a distance scale L; they show that $\ln (kd)$ in Eqs. (17-18) can e ectively be replaced by dl, where $l = \ln (L=d)$. The RG equations therefore take the from

$$\frac{dr_{ii}}{dl} = A_{ii};$$

$$\frac{dt_{ij}}{dl} = A_{ij};$$
(19)

where A_{ii} and A_{ij} are given above. We can write Eqs. (19) in a simpler way. Given the matrix S and the parameters $_i$ (which do not ow under RG), we can de ne a diagonal matrix F whose entries are

$$F_{ii} = \frac{1}{2} ir_{ii}$$
: (20)

Then the RG equations can be written in them atrix form

$$\frac{dS}{dl} = SF^{Y}S \qquad F :$$
 (21)

This is the central result of our work. One can verify from (21) that S continues to remain unitary under the RG ow; it also remains symmetric if it begins with a symmetric form.

W e note also that the form of (21) remains unchanged if S is multiplied either from the left or from the right by a diagonal unitary matrix with entries of the form

$$U_{ii} = e^{i_i}; \qquad (22)$$

where the real numbers $_{\rm i}$ are independent of the length parameter l. The xed points discussed below will therefore also remain unchanged under such phase transformations. We will generally not distinguish between S-matrices which dier only by such transformations.

V.FIXED POINTS AND STABILITY ANALYSIS

W e will now study the RG ow in som e detail. W e will consider the case of three wires for convenience, although much of the discussion below can be generalized to more than three wires. Let us rst nd the xed points of Eq. (21). The required condition is that $SF^{y} = FS^{y}$, i.e., that SF^{y} is herm it in. It is easy to see that the six cases I-VI considered above are all xed points of the RG. In addition, there is another xed point which we will call case V II. For the physically interesting situation in which all the _i are positive, this case is described as follows. W e rst de ne a quantity a as

$$a = \frac{1}{\frac{P_{3}}{1} + 1} :$$
 (23)

Then the xed point S-m atrix has the entries

$$r_{ii} = \frac{a}{r} \text{ for all } i;$$

$$r \frac{i}{t_{ij}} = (1 \frac{a}{i})(1 \frac{a}{j}) \text{ for all } i; j: (24)$$

It is possible to obtain a fam ily of xed points related to the above by multiplying the various am plitudes by som e phases as discussed in Eq. (22). However, we will mainly consider the above form of case V II for sim plicity. Note that for the case of equal interactions in the three wires (i.e., all the $_{\rm i}$ equal to each other), and = 0, the xed point is a well-known S-matrix whose entries are $r_{\rm ii}$ = 1=3 for all i, and $t_{\rm ij}$ = 2=3 for all i; j. This is symmetric under all possible permutations of the three wires, and has them axim um transmission (in all channels simultaneously) allowed by unitarity.

Having found the xed points of the RG equations, we can study their stabilities. Let us write a xed point of the S-m atrix $as S_0$, and a sm all deviation from this as the m atrix S_1 , where is a sm all real parameter. Given S_0 , we are interested in noting the various ow directions' S_1 such that Eq. (21) takes the simple form

$$\frac{d}{dl} = ; \qquad (25)$$

where is a real number. The solution of this equation is (1) = (0) $\exp(1)$, where (0) is given by the deviation

of the S-matrix from S₀ at the microscopic (e.g., lattice) scale. Thus < 0 indicates that S is stable against a perturbation in the direction of the corresponding S₁, while > 0 indicates an instability in the direction of the corresponding S₁. We now consider the various xed points in turn. All the xed points have directions in which = 0 corresponding to the phase rotations of the S-matrix described in Eq. (22). We will ignore these directions in the following discussion.]

(a) Case I: This turns out to be stable against perturbations in all directions. There are three directions in which takes the values (1 + 2)=2, (2 + 3)=2 $(_1 + _3)=2$ respectively. These are negative since and we are assuming that the interactions in all the wires are repulsive. Note that this result agrees, to st order in the i, with the exact results one obtains from bosonization. The operator which tunnels a particle from wire 1 to wire 2 has the scaling dimension $(K_1 + K_2) = (2K_1K_2)$. For weak interactions, this is equal to $1 + (_1 + _2)=2$. Under a RG ow, therefore, the coe cient of the tunneling operator satis es Eq. (25) with = $(_1 + _2)=2.$ (b) Cases II-IV: Case II has two stable directions, both with = $_3=2$ (these correspond to tunneling from wire 3 to wire 1 or wire 2), and one unstable direction with = (1 + 2)=2 corresponding to relation between wires 1 and 2. These results also agree, to rst order in the i, with those obtained from bosonization. For tunneling from wire 3 to wire 1, the operator has the dimension $1=(2K_3) + (K_1 + 1=K_1)=4$; this is equal to $1 + _3=2$ to rst order in the i_{i} and therefore gives = ₃=2. A weak re ection between wires 1 and 2 has the dimension $(K_1 + K_2)=2$ which is equal to 1 $(_1 + _2)=2$ to rst order. This gives a ow with = $(_1 + _2)=2$ which goes in the direction of case I. The RG ows in cases III and IV can be worked out sim ilarly.

(c) Cases V - V I: Case V has three unstable directions with = $_1=2$, $_2=2$ and $_3=2$ respectively. The three directions give ows towards cases II, III and IV. However, if we start out with an appropriate linear combination of the three directions, we can ow directly to case I. Similarly, one can work out the ows for case V I.

(d) Case V II: The stability of ows near this xed point appears to be di cult to study in general. However, the case of equal interactions, 1 = 2 = 3 = 1, can be studied more easily. It has one unstable direction with

= which ows in the direction of case I (this is discussed further in Eq. (35) below), and two unstable directions with = 2 = 3 which ow towards one of the four cases I - IV depending on the precise choice of the initial direction. Further, for appropriately chosen directions of the initial ow, one can go from cases V and VI to case V II. Near case V II, these correspond to two stable directions with = .

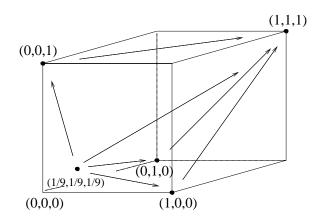


FIG.3. Schem atic diagram of the various tim e-reversal invariant xed points for the 3-wire junction problem. Cases I-IV and V II are indicated as (1,1,1), (0,0,1), (0,1,0), (1,0,0) and (1/9,1/9,1/9), where the sets of three num bers denote the modulus squared of the diagonal entries of the respective S-m atrices. RG ows between the various xed points are indicated by the arrow s.

Based on the above, we can state the ow diagram in the space of all S-m atrices as follows. In general, case I is the most stable. Cases II, III and IV are only unstable to a ow towards case I. Cases V and VI are unstable to ow stowards cases I-IV. Finally, for the case of equal interactions $_{i}$, case V II is unstable to ow towards cases I - IV, and cases V and VI are also unstable to a ow towards case V II (if one starts out in the appropriate direction). We have veried this ow diagram numerically by starting from a number of S-m atrices close to the various xed points and letting them evolve according to Eq. (21).

We thus see that the ow diagram for the case of 3 wires (with repulsive interactions on all the wires) is much richer than in the case of two wires. In the latter case, there are only two xed points, a stable one at $j_{11}j = j_{22}j = 1$ (two disconnected wires), and an unstable one at $j_{12}j = j_{21}j = 1$ (a perfectly transmitting wire). The RG ow simply goes from the rst point to the second [1,9].

VI.CONDUCTANCE OF A THREE-W IRE SYSTEM

H aving studied the S-m atrix for a three-wire system as a function of the RG distance scale l, we can now discuss the conductance of this system . We will assume that the three wires, instead of being really sem i-in nite, are connected to three Ferm i liquid leads (with the interaction parameter being given by K = 1) at a large distance from the junction. We will also assume that there is only one transverse channel of spinless ferm ions in each wire; in this band, there is a resistance of e^2 =h at the contacts between the leads and the wires [10]. A lthough the contacts can them selves scatter the ferm ions [5], we will ignore such e ects here.

W e take the ferm ions in all the leads to have the sam e Ferm i energy $E_{\rm F}$, and the net current on all wires to be zero in the absence of any applied voltage on the leads. Now suppose that the voltage is changed by a sm allam ount $V_{\rm i}$ on lead i. Then the net current owing out of wire i will satisfy the linear relationship [11,10]

$$I_{i} = \frac{e^{2}}{h} \prod_{j=1}^{X^{3}} T_{ij}V_{j}; \qquad (26)$$

where the T_{ij} (for $i \in j$) de ne the various transm ission probabilities, and $T_{ii} + 1$ denote the rejection probabilities. These are related to the S-m atrix at the junction as follows

$$T_{ij} = \mathbf{j}_{ij}\mathbf{j}^{j} \text{ for } i \in \mathbf{j};$$

and
$$T_{ii} = \mathbf{j}_{ii}\mathbf{j}^{j} \quad 1: \qquad (27)$$

Since the unitarity of the S-m atrix in plies that

$$\dot{\mathbf{j}}_{ii}\dot{\mathbf{j}}^{2} + \dot{\mathbf{j}}_{ij}\dot{\mathbf{j}}^{2} = 1;$$
 (28)

we see from (26) that the currents I_j do not change if all the voltages V_i are changed by the sam e am ount. W hen a sm all voltage V_i is applied on lead i in addition to the Ferm i energy, it increases the number of incoming ferm ions on that lead by an am ount given by eV_i times the density of states in energy per unit length. For noninteracting spinless ferm ions in one dimension, the density of states in a continuum theory is given by

$$(E_F) = \frac{1}{2 hv_F};$$
 (29)

where v_F is the Ferm i velocity. We assume this expression for (E_F) to be the same on all leads. In the absence of any scattering from the contact i or from in purities inside wire i, these ferm ions will travel ballistically towards the junction where they will be either rejected back or transmitted to one of the other two wires. Follow-ing that, the ferm ions again travel ballistically till they

em erge from one of the three wires. The outgoing currents are therefore given by ev_F times the extra number of electrons coming in on wire i times the appropriate transmission coe cients on the other two wires and the relation coe cient (subtracted from the incoming current) on wire i.

W e can now compute the conductance by setting, say, w ire 3 to be the potential probe, i.e., $I_3 = 0$ [11]. Then, using the set of equations (26)-(28) given above, the corresponding three-term inal relations are found to be

$$G_{12;13} = \frac{I_1}{V_1 V_3} = \frac{e^2}{h} (T_{12} + T_{13} + \frac{T_{12}T_{13}}{T_{32}});$$
 (30)

$$G_{12;23} = \frac{I_1}{V_2 V_3} = \frac{e^2}{h} (T_{12} + T_{32} + \frac{T_{12}T_{32}}{T_{13}});$$
 (31)

where $I_1 = I_2$, and the two-term inal conductance is given by

$$G_{12;12} = \frac{I_1}{V_1 \quad V_2} = \frac{e^2}{h} (T_{12} + \frac{T_{13}T_{32}}{T_{13} + T_{32}}) : \quad (32)$$

In the above conductance expressions, we have employed the standard convention for specifying the current (rst pair of indices) and voltage (second pair of indices) leads. It is worth noting the incoherence introduced in $G_{12;12}$ through the non-zero transm issions of carriers T_{13} and T_{32} into the additional arm (here, wire 3). The conductances given in Eqs. (31) and (32) will ow under RG following Eq. (21). Let us begin with some S-m atrix at a m icroscopic distance scale d (such as the spacing between the sites in a lattice m odel). The RG ow in (21) is valid till the logarithm ic length scale reaches a physical long-distance cut-o. The appropriate cut-o in this problem is the smaller of the scales $\ln(L_1=d)$ (where L_1 is the length of wire i from the junction to its lead) and $\ln(L_T=d)$, where

$$L_{T} = \frac{hv_{F}}{k_{B}T} ; \qquad (33)$$

with T being the temperature [5]. For simplicity, let us consider the case of high temperature where L_T is smaller than all the wire lengths L_i , but larger than the microscopic length d. Then the RG ow has to be stopped at the scale $l_T = \ln (L_T = d)$ since there is no phase coherence at distance scales larger than this. Now let us suppose that at the microscopic level, the S-matrix deviates slightly from a xed point S_0 by an amount (0)S₁, where S_1 is an unstable direction with > 0. Then at the scale l_T , the deviation is given by

dS (
$$L_{\rm T}$$
) = $\frac{L_{\rm T}}{d}$ (0)S₁: (34)

W e thus see that the deviations from S_0 will grow as 1=T as the tem perature decreases. O focurse, this is only true as long as the deviation is not too large, since Eq. (25)

is only valid to rst order in . These power-law dependences of the conductances on the tem perature should be observable experimentally if a three-wire system can be fabricated.

As a speci c example, consider case V II in which S_0 has $r_{ii} = 1=3$ and $t_{ij} = 2=3$. If all the interactions are equal, with $_i =$, we saw above that this is unstable to a perturbation towards case I (three disconnected wires) with =. The small deviation which takes case V II towards case I is given by

$$ds = \begin{pmatrix} 0 & i4 & 3^2 & i & 15^2 = 2 & i & 15^2 = 2 \\ i & 15^2 = 2 & i4 & 3^2 & i & 15^2 = 2 & A \\ i & 15^2 = 2 & i & 15^2 = 2 & i4 & 3^2 \\ \end{pmatrix}$$
(35)

to second order in the real parameter . We have gone up to second order so as to calculate the correction to T_{ij} which only begins at that order. Namely, $t_{ij}=2=3+i$ 15 $^2=2$, which gives $T_{ij}=4=9$ 9^2 . Since = , the deviation of T_{ij} from 4=9 will grow as 2 $1=T^2$ as the tem perature is reduced. For example, the two-term inal conductance in this case will be

$$G_{12;12}^{VII} = \frac{e^2}{h} \left(\frac{2}{3} - \frac{27}{2}c_1T^{-2}\right); \qquad (36)$$

where c_1 is some constant, while the three-term inal conductances for this case are identical and are given by

$$G_{12;13}^{VII} = \frac{e^2}{h} \left(\frac{4}{3} - 27 g T^2\right) / 2G_{12;12}^{VII}$$
(37)

T hus the power-law dependence on $T\,$ can provide information on the strength of the interaction $\,$.

VII.FOUR-TERM INAL CONDUCTANCE OF A QUANTUM W IRE

We consider here the case of the four-term inal conductance of a quantum wire of nite length L measured at high tem peratures such that the therm allength L_T (= $hv_F = k_B T$) > 1.

The quantum wire is connected to two reservoirs 1 and 2 which act as current probes. In addition, the quantum wire is also weakly coupled to two voltage probes 3 and 4 via identical barriers with tunneling am plitudes 1. We consider the current and voltage probes to be sem i-in nite, two-dimensional electron gas (2DEG) Ferm i liquid reservoirs; these can be modeled as Tom onaga-Luttinger leads with interaction param eter $K_{L} = 1$, i.e., in our case of very weak interactions, L = 0. The quantum wire is itself modeled as a TLL with weak repulsive interactions characterized by a param eter w. We can now see that this case is akin to that of a system of two 3-wire junctions with a common arm (of nite length L and with L L_{T}). Further, one arm in each of the two 3-wire junctions is coupled to the other two through a weak tunneling am plitude; this case

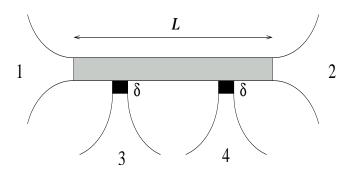


FIG.4. Schem atic diagram of a quantum wire of length L (grey shaded region) connected to the two current probes (1 and 2) and two voltage probes (3 and 4). The voltage probes are very weakly coupled to the quantum wire via tunneling barriers of am plitude 1 (black shaded regions).

thus falls som ewhere between the xed point I and any one of the xed points II-IV discussed earlier.

Following the analysis of Ref. [11], we can write the four-term inal conductance of this system as

$$G_{12;34} = \frac{e^2}{h} T_{12} \frac{(T_{31} + T_{32})(T_{41} + T_{42})}{T_{31}T_{42} - T_{32}T_{41}}$$
(38)

where $T_{\rm ij}$ stands, as usual, for the transm ission from lead i to lead j. As transm ission from lead 1 to lead 2 can take place through paths which never cross any of the two tunneling barriers, we can write (to low est order in) $T_{12} = T_{12}^{(0)}$. Transm ission from lead 3 to lead 1 can take place, to low est order in , through a path that crosses one tunneling barrier; this gives $T_{31} = T_{31}^{(1)}$, where $T_{31}^{(1)}$ is a positive num ber of order 1. Sim ilarly, even the sim – plest path from lead 3 to lead 4 needs the crossing of two barriers, giving $T_{34} = {}^2T_{34}^{(2)}$. Thus, keeping only term s till order 2 , we can write G $_{12;34}$ as

$$G_{12;34} = \frac{e^2}{h} T_{12}^{(0)} \frac{(T_{31}^{(1)} + T_{32}^{(1)})(T_{41}^{(1)} + T_{42}^{(1)})}{T_{31}^{(1)}T_{42}^{(1)} T_{32}^{(1)}T_{41}^{(1)}}$$
(39)

The four-term inal resistance $R_{12;34} = 1 = G_{12;34}$ lies in the range $h = (e^2 T_{12}^{(0)})$ $R_{12;34}$ $h = (e^2 T_{12}^{(0)})$. The RG ow of the tunneling barriers will take place as given earlier, but with a parameter which is dependent on the interaction parameter of the quantum wire W (note that L = 0 for all the four probes). Now, as we have identical barriers connecting two identical voltage probes 3 and 4 to the quantum wire, the various wire-voltage probe transm issions, such as $T_{31}^{\,(1)}$; $T_{32}^{\,(1)}$; $T_{41}^{\,(1)}$ and $T_{42}^{\,(1)}$, will have identical power-law dependences on the tem perature. Thus, in the expression (39) given above, the only tem perature dependence of G_{12;34} will com e from the RG ow of the transmission ${\rm T}_{12}^{\,(0)}$, since all the temperature dependences com ing from the wire-voltage probe transm issions will cancel out. Further, as the two-term inal $(e^2 = h) T_{12}^{(0)}$ to low est order in , conductance G_{12:12}

we can see that the tem perature dependences of G $_{12;12}$ and G $_{12;34}$ are identical!

In a recent experim ent [12], Picciotto et al. m easured both the two-term inal resistance $R_{12;12} (= 1=G_{12;12})$ as well as the four-term inal resistance R_{12;34} of a cleavededge overgrowth quantum wire in a GaAs-AlGaAs heterojunction using two weakly coupled voltage probes. They found that while R_{12;12} is quantized in integer multiples of $h=2e^2$, $R_{12;34}$ uctuated above and below zero and nally vanished as the gate voltage was made less negative. R_{12:34} uctuates about zero because its value depends critically on the invasive nature of the probes (i.e., on the precise values of the transm issions $T_{31}^{\,(1)}$; $T_{32}^{\,(1)}$; $T_{41}^{\,(1)}$ and $T_{42}^{\,(1)}$), and the fact that $R_{12;34}$ h=($e^2 T_{12}^{(0)}$). The average value $h = (e^2 T_{12}^{(0)})$ of R_{12:34} vanishes due to the fact that the intrinsic resistance of a quantum wire without any defects or in purities com es from its connections to the 2DEG reservoirs, i.e., the so-called contact resistances [12]. Our prediction of the identical power-law variations of $G_{12;12}$ and $G_{12;34}$ with temperature can also be tested in such an experim ent by taking m easurem ents of the two conductances at various tem peratures but at a xed value of the gate voltage (this holds the values of the various transm issions T_{ii} xed at the m icroscopic level, and their observed values will vary with the tem perature through the RG equations).

VIII.ANALYSISOF A FOUR-W IRE SYSTEM

We can carry out a similar analysis of the xed points and the conductance for a system of four wires meeting at a junction. In this section, we will assume for simplicity that the interaction parameters $_i =$ are equal on all the wires.

Let us rst consider the xed points of the RG equations (21) for a four-wire system. To begin with, one can readily identify 4!=24 xed points which are naturalgeneralizations of the 3!=6 xed points (cases I-V I) that we found above for the three-wire system. These

xed points correspond to all the possible ways in which each row (or column) of the S-m atrix at the junction has only one non-zero entry whose modulus is equal to 1. We thus have the following possibilities.

(a) The simplest case is one in which all the four wires are disconnected from each other. The S-m atrix is then diagonal, with all the diagonal entries having unit m od-ulus.

(b) There are six cases in which two of the wires are disconnected from all the others, while the remaining two wires transm it perfectly into each other.

(c) There are three cases in which pairs of wires (say, 1,2 and 3,4) transm it perfectly into each other.

(d) There are eight cases in which one wire (say, wire 4) is disconnected from the other three, while the other three

w ires (1, 2 and 3) are connected to each other cyclically as in Cases V and VI for the three-w ire system .

(e) There are six cases in which the four wires transmit perfectly into each other in a cyclical way, such as, 1 into 2, 2 into 3, 3 into 4, and 4 into 1.

W e note that the 10 cases given in (a-c) are invariant under time reversal if we choose all the entries of the Sm atrix to be real; these 10 cases allow bosonization to be done. The 14 cases in (d-e) necessarily violate timereversal invariance; they can also be bosonized.

In addition to the 24 cases given above, there are 5 m ore xed points of the RG equations. Four of these correspond to situations in which one of the wires (say, 4) is disconnected from the other three, while the other three wires (1, 2 and 3) have the completely symmetric and m axim ally transmitting S-matrix of the form given in Case V II above. The flth case corresponds to the case in which the four wires have a completely symmetric and maxim ally transmitting S-matrix; the diagonal and o - diagonal entires of this matrix are given by 1=2 and 1=2 respectively.

We thus have a total of 29 xed points for a four-wire system in contrast to 7 xed points for the three-wire system. In addition to these 29 cases, we will now see that the four-wire system has some new classes of xed points which do not exist for system s with less than four wires. Namely, there exist two-parameter families of xed points in the four-wire system. In contrast to these, the xed points of the two- and three-wire systems are all isolated points, i.e., they have no variable parameters (apart from some trivial phases).

A lthough we have not studied all the two-param eter fam ilies of xed points in the four-wire system, we can exhibit some of these fam ilies explicitly. Two examples are given by

$$S = \begin{pmatrix} 0 & x_1 & iy_1 & 0 \\ B & x_2 & 0 & 0 & iy_2 \\ 0 & iy_2 & 0 & 0 & x_2 \\ 0 & iy_1 & x_1 & 0 \end{pmatrix}^{1}$$
(40)

where x_i and y_i are four realnum bers satisfying the constraints $x_1^2 + y_1^2 = x_2^2 + y_2^2 = 1$, and

$$S = \begin{bmatrix} 0 & & & 1 \\ 0 & x & y & z \\ B & x & 0 & z & y \\ 0 & y & z & 0 & x \\ z & y & x & 0 \end{bmatrix}$$
(41)

where x; y and z are three real numbers satisfying the constraint $x^2 + y^2 + z^2 = 1$. [It is easy to see that these are xed points of Eq. (21) since the diagonal matrix F is equal to zero for these families]. Note that these two families have some members in common which are obtained by setting $x_1 = x_2 = x$, $y_1 = y_2 = y$ and z = 0, and then performing some phase transformations. Further, these families include some of the xed points given earlier as special cases.

The two-parameter families are xed points of the RG equations (21) which are only valid to rst order in the interaction parameter . Do they remain xed points if we go to higher orders in ? One way to answer this question is to use the technique of bosonization. As remarked earlier, it does not seem possible to bosonize an interacting fermionic theory for all possible S-m atrices. Fortunately, the two-parameter families described above contain some special points at which bosonization can be done. For instance, consider the S-m atrix

$$S = \begin{bmatrix} 0 & 1 & 0 & 0 \\ B & 1 & 0 & 0 & 0 \\ 0 & 0 & 0 & 1 & A \\ 0 & 0 & 1 & 0 \end{bmatrix}$$
(42)

which corresponds to wires 1,2 (and wires 3,4) transm itting perfectly into each other. W e can bosonize this system; for equal interaction strengths on all the wires, the bosonic theory will have the same parameter K for all wires. We then turn on small perturbations corresponding to either $y_1; y_2$ in the fam ily given in (40), or y; zin the fam ily given in (41). These correspond to hopping at the junction between wire 1 (or 2) and wire 3 (or 4). All these hopping operators have the scaling dimension (K + 1=K)=2 which is necessarily larger than 1; hence they are irrelevant, and the perturbed S-m atrices will therefore ow back to Eq. (42) under RG. For weak interactions with K = 1, we see that the scaling dimension diers from 1 only at order ² and higher, which explains why these small perturbations look like xed points at order .

We therefore conclude that the two-param eter fam ilies given above are generally not xed points of the exact (i.e., to all orders in the interaction strengths) RG equations. A lthough we have shown this only in the vicinity of some bosonizable points, it is plausible that this statement will also be true for most other members of the fam ilies. However, this does not rule out the possibility that there may be non-trivial and isolated members of these fam ilies which are xed points of the exact RG equations. Let us present a plausible example of such a non-trivial xed point. We consider a one-param eter fam ily of S-m atrices of the form

$$S = \begin{bmatrix} 0 & x & iy & 0 \\ B & x & 0 & 0 & iy \\ 0 & iy & 0 & 0 & x \\ 0 & iy & x & 0 \end{bmatrix}^{1}$$
(43)

where $x^2 + y^2 = 1$ and 0 x;y 1. The two endpoints of this fam ily given by (x;y) = (1;0) and (0;1) are bosonizable because they consist of pairs of perfectly transm itting wires (1,2 and 3,4 at the rst point, and 1,3 and 2,4 at the second point) which transm it perfectly into each other. W ithin this one-parameter fam ily, the bosonization approach discussed above shows that both the end-points are stable, since small perturbations from them (corresponding to turning on $y_1 = y_2$ in Eq. (40)) are irrelevant. The simplest possibility therefore is that there is one unstable xed point which lies between the two end-points; since the interaction strengths in all the wires are equal, this xed point is likely to be at the half-way point given by x = y = 1 = 2. However, we are unable to directly verify that this is an unstable xed point of the exact RG equations since this point does not seem to be bosonizable.

To sum marize, we see that the pattern of xed points and RG ows for a four-wire system is in mensely more complicated than those of two- and three-wire systems. We do not have a complete classication of the xed points for a four-wire system. Some families of Smatrices which appear to be xed points at rst order in the interaction strengths turn out not to be xed points at higher orders.

W e now turn to a discussion of the tem perature dependences of the conductance corrections. Our arguments will be very similar to those given for a three-wire system at the end of Sec. V I.W e consider the vicinity of one particular xed point of the four-wire system, namely, the completely symmetric and maximally transmitting S-matrix. Let us perturb this in a completely symmetric way, so that the entries of the S-matrix are given by

$$r_{ii} = \frac{1}{2} + i3 \quad 3^2;$$

 $t_{ij} = \frac{1}{2} + i \quad 5^2;$ (44)

to second order in the small real number . [This perturbation will eventually lead to the situation in which all the four wires are disconnected from each other]. Using Eqs. (21), we nd that the perturbation initially grows as in Eq. (34) with = . The arguments presented in Sec. VI therefore in ply that at high temperature, the transm ission probabilities $T_{ij} = 1=4$ 4^2 vary with tem – perature as

$$T_{ij} = \frac{1}{4} \quad Q T^{2} ;$$
 (45)

where c_2 is some constant.

We can also compute the four-term inal conductances of this system by following the arguments of Ref. [11] and those given in Sections VI and VII. For a set of four probes fm n k lg (which will be a permutation of f1 2 3 4g), we can write the relation between the currents $I_m = I_1 = I_1$, $I_k = I_1 = I_2$ and the voltages $V_1 = (m_n) = V_2 = (k_1) = W$ (where i denotes the chemical potential of the ith probe) as

where

The general expression for the four-term inal resistance $R_{m\,n\,;kl} = 1=G_{m\,n\,;kl}$ (which has six permutations) can then be written as

$$R_{mn;kl} = \frac{h}{e^2} \frac{T_{km} T_{ln} - T_{kn} T_{lm}}{D}; \quad (48)$$

where D = ($_{11} _{22} _{12} _{21}$)=P. From here, we can easily work out the four-term inal resistances for the case of the completely symmetric and maximally transmitting S-matrix (using Eq. (44)). In this case however, as $_{12} = _{21} = 0$, all four-term inal resistances will sim – ply give $R_{mn;k1} = 0$. This result is interesting for the following reason: while all the four-term inal resistances $R_{mn;k1}$ vanish if the system is exactly at the fully sym – metric xed point, the above suggests that they continue to stay zero as long as interactions are weak and the RG ow s of the various elements of the S-matrix take place in a symmetric fashion. This means that in this case, the various $R_{mn;k1}$ will continue to be zero even as the temperature is varied.

The other interesting (and experimentally relevant) case for which conductances can be computed is that of two crossed, perfectly transmitting quantum wires which are connected via the tunneling of electrons at one point. This point is characterized by the S-matrix given earlier in Eq. (42). We have already seen that the hopping between the two wires is an irrelevant process. Further, we can treat any small relection in either of the two perfectly transmitting wires perturbatively; from the work of K ane and F isher [1], it is known that such perturbations are relevant and will grow so as to cut the wires (i.e., they ow under RG towards the perfectly relevant to unity). Thus, there is nothing new to be found in the computation of the conductances in this case.

F inally, we would like to mention the work of K om nik and Egger on crossed quantum wires [13]. In addition to the hopping operators considered above, they study the e ects of a density-density interaction between the two wires at the point where they cross; they show that such an interaction can have a non-trivial e ect if the interactions in the wires are su ciently strong. However, such strong interactions are beyond the purview of our analysis; for the case of weak interactions considered here, such interactions are irrelevant.

IX.TOMONAGA-LUTTINGER LIQUIDSW ITH SPIN

It is not di cult to extend all the results above to the case of interacting ferm ions with spin. Let us rst discuss the form of the interactions. We again begin with a short-range interaction as in Eq. (4) where the density is now a sum of the form

$$= {}^{Y}_{"} {}^{"}_{"} + {}^{Y}_{\#} {}^{\#}_{\#} : \qquad (49)$$

The second-quantized elds " and " have expansions near the Ferm ipoints of the form given in Eq. (3). (We assume that there is no magnetic eld, so that spin-" and spin-" electrons have the same Ferm ienergy). Following the arguments leading up to Eq. (6), we can show that

$$\begin{array}{c} \underset{Z}{\overset{\text{int}}{=}} \\ \underset{Z}{\overset{\text{int}}{=}} \\ \text{dx} \\ \text{dx} \\ \text{int} \\ \underset{Z}{\overset{\text{int}}{=}} \\ \text{dx} \\ \text{int} \\ \text{int}$$

where

$$g_1 = \nabla (2k_F)$$
;
and $g_2 = g_4 = \nabla (0)$: (51)

Yue et al show that the backscattering interaction govemed by g_1 leads to a logarithm ic renorm alization of the interaction parameters g_1 and g_2 [7]; we will ignore that e ecthere since it plays no role to rst order in the g_1 . We can also ignore the e ects of the g_4 term; it renorm alizes the velocity, but it does not contribute to the re ection from the Friedel oscillations which is what leads to the RG ow of the S-matrix.

If there is a non-zero re ection amplitude r on w ire i, then there w ill again be Friedel oscillations given by Eqs. (11-12) for both spin-" and spin-# electrons. Then the interactions w ill lead to scattering of incom ing electrons to outgoing electrons (and vice versa); this is given by the follow ing H artree Fock decom position of (50),

(This may be compared with Eq. (13) for spinless fermions). We see from Eq. (52) that the spin-" and spin-# electrons have decoupled from each other in this approximation. Hence the RG analysis given above for spinless fermions will go through similarly here. The only di erence is that the interaction parameter is now given by

$$= \frac{\vec{\nabla}(0) \quad 2\vec{\nabla}(2k_{\rm F})}{2 \quad hv_{\rm F}}; \qquad (53)$$

instead of = $[V(0) \quad V(2k_F)] = (2 \quad hv_F)$ in the spinless case. We thus see that to rst order in the interaction, the analysis remains essentially the same for spinless and spinful ferm ions. Finally, the conductances have factors of 2e²=h for spinful ferm ions in place of e²=h for spinless ferm ions but have sim ilar tem perature power-laws dependent on the interaction parameter de ned above. In fact, it should be possible to detect such power-laws in existing 3-arm and 4-arm quantum wire systems built by the voltage-gate patterning on the 2DEG in GaAs heterojunctions [14,15]. W hile the early experiments with such system s focussed on carrier transport in the presence of an external magnetic eld and the e ects of geom etry [14], m easuring the two-term inal, three-term inal and four-term inal conductances for xed values of the various gate voltages but at di erent tem peratures should again reveal identical power-law variations as discussed earlier for spinless ferm ions. In fact, sim ilar studies using the technique developed by Shepard etal. [15] for directly m easuring the transm ission m atrix elements of such junctions should be able to show the tem perature power-law variations of the various transm ission probabilities.

X.CONCLUSION

In this work, we have derived the RG equations for a general S-m atrix at the junction of several quantum wires, and we have discussed the consequences of these equations for the conductances across the system . The RG ows are a result of interactions in the wires; there is no ow if the interaction parameters i are all zero. Our results di er considerably from those of Ref. [6] who nd RG ows even in the absence of interactions in the wires. This di erence seems to be due to their model of the junction; they have a spin-1=2 degree of freedom sitting there which interacts with the electrons on the w ires. This gives rise to a nontrivial interacting m odel of the K ondo type even if there are no interactions in the wires. Their ow diagram is therefore quite di erent from ours. Further, they only consider the case where both the S-m atrix and the interactions are symmetric under all possible permutations of the wires; how ever they are able to use bosonization to study the case of an arbitrary interaction strength.

O urwork can clearly be generalized to the case ofm ore than four wires meeting at a junction. The RG ow diagram will rapidly get more complicated as the number of wires increases. Physically, we expect the cases of three and four wires to be the easiest to study; these two cases arise in the experiments discussed earlier [14,15] as well as in the cases of Y-branched carbon nanotubes [16] and crossed carbon nanotubes [17].

Besides the restriction to weak interactions in the wires, our work has the limitation that we have assum ed linear relations between the incom ing and outgoing ferm ion elds. In principle, other interesting things can happen at a junction. For instance, there may be And reev re ection in which a ferm ion striking the junction from one wire is relected back as a hole while two ferm ions are transmitted into some of the other wires [6]. Even more complicated things may occur for the case of spinful ferm ions. Som e of these phenom ena can be expressed as boundary conditions at the junction in the bosonic language, but not in the ferm ionic language. W e expect that such bosonic boundary conditions will require a method of analysis which is very dierent from the one which we have used to study the ferm ion S-m atrix in this paper.

Finally, it remains a challenging problem to see if some of the non-trivial xed points that we have found (such as case VII for the three-wire case) can be bosonized for arbitrary interaction strengths. Bosonizing such points would lead to a much more complete picture of the RG ows besides increasing our understanding of conform al eld theories with boundaries.

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